



N-Channel 100-V (D-S) MOSFET

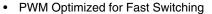
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
100	0.034 at V _{GS} = 10 V	7.8			
	0.040 at V _{GS} = 6.0 V	7.2			

FEATURES

 Halogen-free According to IEC 61249-2-21 Available



 New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile



100 % R_g Tested



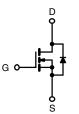
HALOGEN

FREE

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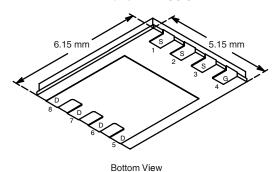
APPLICATIONS

- · Primary Side Switch for High Density DC/DC
- Telecom/Server 48 V, Full-/Half-Bridge DC/DC
- Industrial and 42 V Automotive



N-Channel MOSFET

PowerPAK® SO-8



Ordering Information: Si7454DP-T1-E3 (Lead (Pb)-free)

Si7454DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T	A = 25 °C, unles	ss otherwise n	oted		
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	100		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C	I _D	7.8	5.0	А
Continuous Drain Current (1) = 150 °C)	T _A = 85 °C		5.7	3.6	
Pulsed Drain Current		I _{DM}	30		^
Avalanche Current	L = 0.1 mH	I _{AS}	25 31		
Single Avalanche Energy (Duty Cycle ≤ 1 %)	L = 0.1 IIII	E _{AS}			mJ
Continuous Source Current (Diode Conduction) ^a	I _S	4.0	1.6	Α	
Maximum Daylar Dissinational	T _A = 25 °C	P _D	4.8	1.9	W
Maximum Power Dissipation ^a	T _A = 85 °C	' D	2.6	1.0	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature)b, c			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manianum lungtion to Ambienta	t ≤ 10 s	R _{thJA}	21	26	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	55	65		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.6	2		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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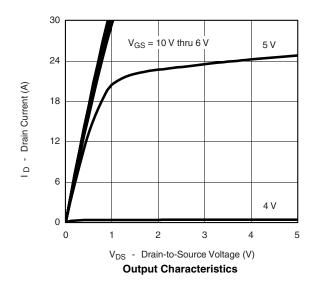


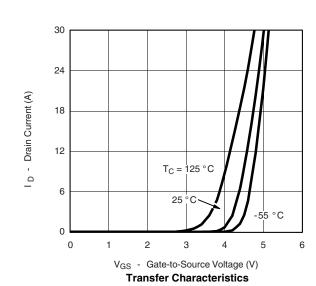
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$			4	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zoro Coto Voltogo Droin Current	I _{DSS}	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$			1			
Zero Gate Voltage Drain Current		V _{DS} = 100 V, V _{GS} = 0 V, T _J = 85 °C		20	μΑ			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
5	В	$V_{GS} = 10 \text{ V}, I_D = 7.8 \text{ A}$		0.028	0.034	0		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 6.0 \text{ V}, I_D = 7.2 \text{ A}$		0.032	0.040	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 7.8 A		25		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 4 A, V _{GS} = 0 V		0.8	1.2	V		
Dynamic ^b								
Total Gate Charge	Q_g			24	30			
Gate-Source Charge	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 7.8 \text{ A}$		7.6		nC		
Gate-Drain Charge	Q_{gd}			5.4				
Gate Resistance	R_g		0.5	1.25	2.2	Ω		
Turn-On Delay Time	t _{d(on)}			16	30			
Rise Time	t _r	t_r $V_{DD} = 50 \text{ V}, R_L = 50 \Omega$		10	20			
Turn-Off Delay Time	$t_{d(off)}$ $I_D \cong 1.0 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 6 \Omega$		35	70	ns			
Fall Time	t _f			20	40			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 4 A, dI/dt = 100 A/μs		50	80			

- Notes: a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



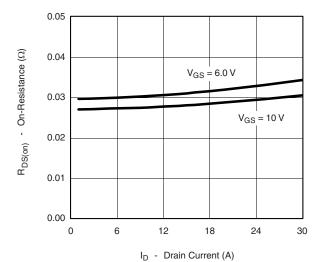




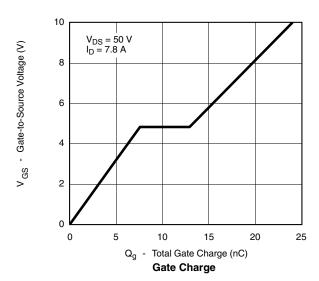


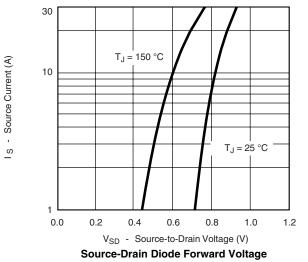


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



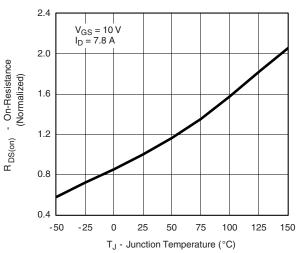
On-Resistance vs. Drain Current



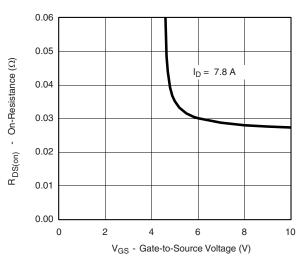


2500 2000 C - Capacitance (pF) Çiss 1500 1000 500 Coss 0 20 10 30 40 50 60 0

V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

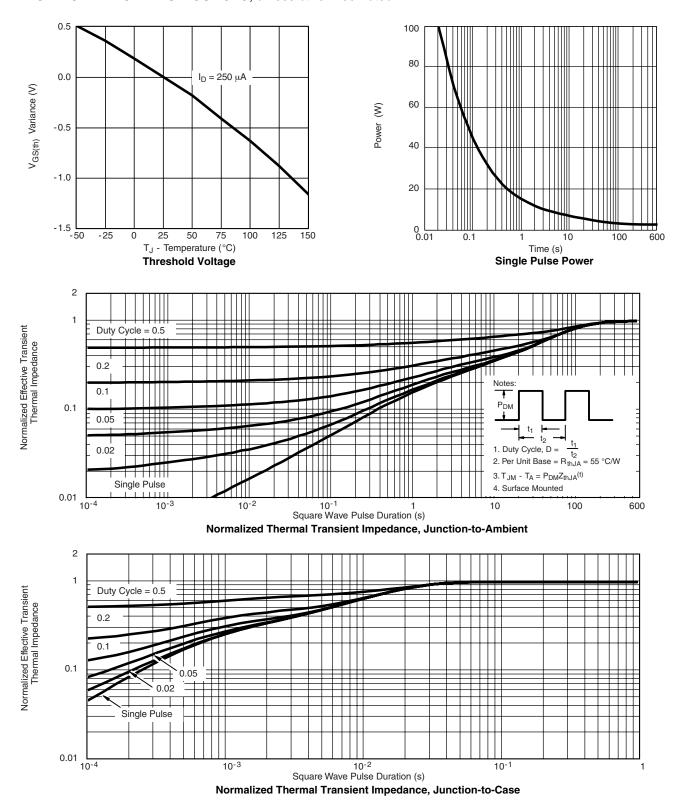


On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



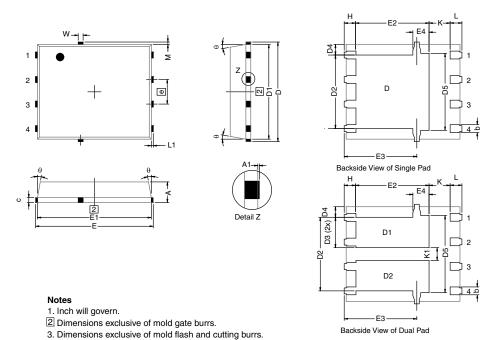
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71618.



ECN: C13-0702-Rev. K, 20-May-13

DWG: 5881

PowerPAK® SO-8, (Single/Dual)

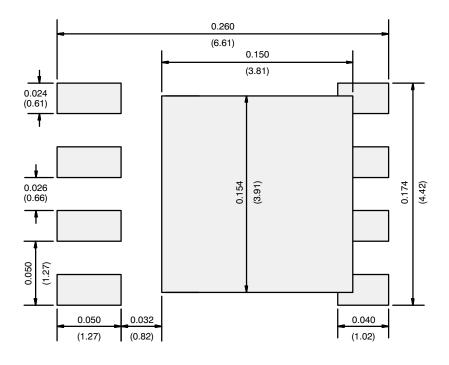


		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.56	3.76	3.91	0.140	0.148	0.154		
D3	1.32	1.50	1.68	0.052	0.059	0.066		
D4		0.57 typ.			0.0225 typ.			
D5		3.98 typ.			0.157 typ.			
Е	6.05	6.15	6.25	0.238	0.242	0.246		
E1	5.79	5.89	5.99	0.228	0.232	0.236		
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144		
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151		
E3	3.68	3.78	3.91	0.145	0.149	0.154		
E4 (for AL product)		0.58 typ.			0.023 typ.			
E4 (for other product)		0.75 typ.			0.030 typ.			
е		1.27 BSC			0.050 BSC			
K (for AL product)		1.45 typ.			0.057 typ.			
K (for other product)	1.27 typ.			0.050 typ.				
K1	0.56	-	-	0.022	-	-		
Н	0.51	0.61	0.71	0.020	0.024	0.028		
L	0.51	0.61	0.71	0.020	0.024	0.028		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
M	0.125 typ.			0.005 typ.				

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RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE



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